


	<h2 style="color: #E67E22;">APTM120U10SCAVG</h2>	
	<b>Hersteller-Teilenummer:</b>	<a href="#">APTM120U10SCAVG</a>
	<b>Hersteller / Marke:</b>	<a href="#">Microsemi</a>
	<b>Teil der Beschreibung:</b>	MOSFET N-CH 1200V 116A SP6
	<b>Datenblätter:</b>	 <a href="#">APTM120U10SCAVG.pdf</a>
	<b>RoHs Status:</b>	Bleifrei / RoHS-konform
<b>Lagerzustand:</b>	New original, Stock Available.	
<b>Liefern von:</b>	Hong Kong	
<b>Versandweg:</b>	DHL/Fedex/TNT/UPS/EMS	
Image may be representation. See specs for product details.		









### Spezifikationen

Teilenummer	<a href="#">APTM120U10SCAVG</a>
Hersteller	<a href="#">Microsemi</a>
Beschreibung	MOSFET N-CH 1200V 116A SP6
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	<a href="#">Require For Quote &amp; Check Stock</a>
VGS (th) (Max) @ Id	5V @ 20mA
Technologie	MOSFET (Metal Oxide)
Supplier Device-Gehäuse	SP6
Serie	POWER MOS 7®
Rds On (Max) @ Id, Vgs	120 mOhm @ 58A, 10V
Verlustleistung (max)	3290W (Tc)
Verpackung	Bulk
Verpackung / Gehäuse	SP6
Betriebstemperatur	-40°C ~ 150°C (TJ)
Befestigungsart	Chassis Mount
Eingabekapazität (Ciss) (Max) @ Vds	28900pF @ 25V
Gate Charge (Qg) (Max) @ Vgs	1100nC @ 10V
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	1200V (1.2kV)
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	116A

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RFQ APTM120U10SCAVG E-Mail: [Info@Y-IC.com](mailto:Info@Y-IC.com)

### Sie können auch interessiert

<b>sein:</b>  <p><b>APTM120TA57FPG</b> Microsemi Corporation MOSFET 6N-CH 1200V 17A SP6-P</p>	 <p><b>APTM120VDA57T3G</b> Microsemi Corporation MOSFET 2N-CH 1200V 17A SP3</p>	 <p><b>APTM120SK68T1G</b> Microsemi Corporation MOSFET N-CH 1200V 15A SP1</p>	 <p><b>APTM120U10SAG</b> Microsemi Corporation MOSFET N-CH 1200V 116A SP6</p>
 <p><b>APTM120TDU57PG</b> Microsemi Corporation MOSFET 6N-CH 1200V 17A SP6-P</p>	 <p><b>APTM20AM04FG</b> Microsemi Corporation MOSFET 2N-CH 200V 372A SP6</p>	 <p><b>APTM120UM95FAG</b> Microsemi Corporation MOSFET N-CH 1200V 103A SP6</p>	 <p><b>APTM120UM70DAG</b> Microsemi Corporation MOSFET N-CH 1200V 171A SP6</p>

### Verwandtes Hot-Keyword

Mehr

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<a href="#">APTM120U10SCAVG Neu</a>	<a href="#">APTM120U10SCAVG Original</a>	<a href="#">APTM120U10SCAVG garantiert</a>	<a href="#">APTM120U10SCAVG RFQ</a>	<a href="#">APTM120U10SCAVG Online bestellen</a>

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